

# SGM7222 High Speed USB 2.0 (480Mbps) DPDT Analog Switch

#### **GENERAL DESCRIPTION**

The SGM7222 is a high-speed, low-power double-pole/double-throw (DPDT) analog switch that operates from a single 1.8V to 4.3V power supply.

The SGM7222 is designed for the switching of high-speed USB 2.0 signals in handset and consumer applications, such as cell phones, digital cameras, and notebooks with hubs or controllers with limited USB I/Os.

The SGM7222 has low bit-to-bit skew and high channel-to-channel noise isolation, and is compatible with various standards, such as high-speed USB 2.0 (480Mbps). Each switch is bidirectional and offers little or no attenuation of the high-speed signals at the outputs. Its bandwidth is wide enough to pass high-speed USB 2.0 differential signals (480Mbps) with good signal integrity.

The SGM7222 contains special circuitry on the D+/D-pins which allows the device to withstand a  $V_{\text{BUS}}$  short to D+ or D- when the USB devices are either powered off or powered on.

The SGM7222 is available in Green TQFN-1.8×1.4-10L, MSOP-10 and UTQFN-1.8 × 1.4-10L packages. It operates over an ambient temperature range of -40 $^{\circ}$ C to +85 $^{\circ}$ C.

#### **APPLICATIONS**

Route Signals for USB 2.0
MP3 and Other Personal Media Players
Digital Cameras and Camcorders
Portable Instrumentation
Set-Top Boxes
PDAs

#### **FEATURES**

• R<sub>ON</sub> is Typically 4.5Ω at 3V

• Low Bit-to-Bit Skew: 50ps (TYP)

Voltage Operation: 1.8V to 4.3V

• Fast Switching Times:

 $t_{ON}$  = 10ns  $t_{OFF}$  = 22ns

Low Crosstalk: -41dB at 250MHz

Power-Off Protection when V<sub>+</sub> = 0V,
 D+/D- Pins can Tolerate up to 5.25V

• High Off-Isolation: -35dB at 250MHz

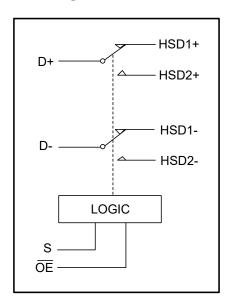
• Rail-to-Rail Input and Output Operation

Break-Before-Make Switching

Extended Industrial Temperature Range:
 -40°C to +85°C

 Available in Green MSOP-10, TQFN-1.8×1.4-10L and UTQFN-1.8×1.4-10L Packages

#### **BLOCK DIAGRAM**





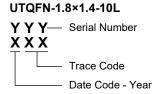
#### PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	ORDERING NUMBER	PACKAGE MARKING	PACKING OPTION
	MSOP-10	-40°C to +85°C	SGM7222YMS10/TR	SGM7222 YMS10 XXXXX	Tape and Reel, 3000
SGM7222	TQFN-1.8×1.4-10L	-40°C to +85°C	SGM7222YWQ10/TR	7222	Tape and Reel, 3000
	UTQFN-1.8×1.4-10L	-40°C to +85°C	SGM7222YUWQ10/TR	CAA XXX	Tape and Reel, 3000

#### MARKING INFORMATION

NOTE: XXX = Date Code and Trace Code. XXXXX = Date Code and Vendor Code. MSOP-10 UTQFN-1.8×1.4-1





Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### **ABSOLUTE MAXIMUM RATINGS**

V+ to GND	0V to 4.6V
Analog, Digital Voltage Range	0.3V to (V <sub>+</sub> ) + 0.3V
Continuous Current HSDn or Dn	±100mA
Peak Current HSDn or Dn	±150mA
Junction Temperature	+150°C
Storage Temperature Range	65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
ESD Susceptibility	
HBM	8000V
MM	400V

#### RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range .....-40°C to +85°C

#### **OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

#### **ESD SENSITIVITY CAUTION**

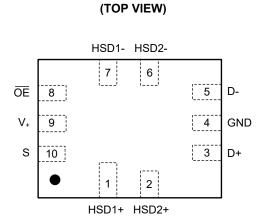
This integrated circuit can be damaged by ESD if you don't pay attention to ESD protection. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

#### **DISCLAIMER**

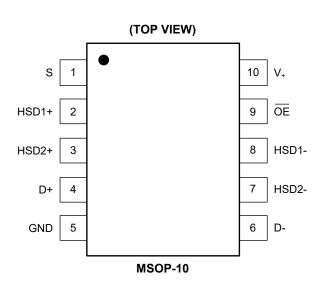
SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.



## **PIN CONFIGURATIONS**







#### PIN DESCRIPTION

PIN					
TQFN-1.8×1.4-10L/ UTQFN-1.8×1.4-10L	MSOP-10	NAME	FUNCTION		
1, 2	2, 3	HSD1+, HSD2+			
3, 5	4, 6	D+, D-	Data Ports.		
7, 6	8, 7	HSD1-, HSD2-			
4	5	GND	Ground.		
8	9	ŌĒ	Output Enable.		
9	10	V <sub>+</sub>	Power Supply.		
10	1	S	Select Input.		

# **FUNCTION TABLE**

ŌĒ	S	HSD1+ HSD1-	HSD2+ HSD2-
0	0	ON	OFF
0	1	OFF	ON
1	×	OFF	OFF

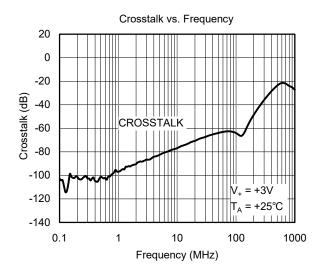
NOTE: Switches shown for logic "0" input.

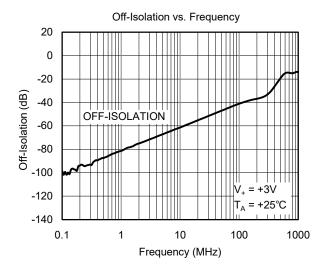
## **ELECTRICAL CHARACTERISTICS**

 $(V_{+} = 1.8V \text{ to } 4.3V, \text{ GND} = 0V, V_{IH} = 1.6V, V_{IL} = 0.5V, \text{ Full} = -40^{\circ}\text{C} \text{ to } +85^{\circ}\text{C}.$  Typical values are at  $V_{+} = 3.3V, T_{A} = +25^{\circ}\text{C}, \text{ unless otherwise noted.})$ 

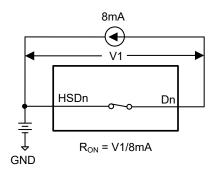
PARAMETER	SYMBOL	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Analog Switch							
Analog I/O Voltage (HSD1+, HSD1-, HSD2+, HSD2-)	V <sub>IS</sub>		Full	0		V <sub>+</sub>	V
On-Resistance	R <sub>on</sub>	$V_{+} = 3V$ , $V_{IS} = 0V$ to 0.4V, $I_{D} = 8mA$ ,	+25°C		4.5	8.5	Ω
On-i tesistance	TON	Test Circuit 1	Full			9	12
On-Resistance Match Between	$\Delta R_ON$	$V_{+} = 3V$ , $V_{IS} = 0V$ to 0.4V, $I_{D} = 8mA$ ,	+25°C		0.15	0.6	Ω
Channels	ΔIXON	Test Circuit 1	Full			1.6	12
On-Resistance Flatness	R <sub>FLAT(ON)</sub>	$V_{+} = 3V$ , $V_{IS} = 0V$ to 1V, $I_{D} = 8mA$ ,	+25°C		1.5	2.0	Ω
On-incesistance i latiless	TFLAT(ON)	Test Circuit 1	Full			2.6	12
Power Off Leakage Current (D+, D-)	l <sub>OFF</sub>	$V_{+} = 0V, V_{D} = 0V \text{ to } 3.6V,$ $V_{S}, V_{\overline{OE}} = 0V \text{ or } 3.6V$	Full			1	μΑ
Increase in I+ per Control Voltage	Ісст	$V_{+} = 3.6V, V_{S} \text{ or } V_{\overline{OE}} = 2.6V$	Full			5	μΑ
Source Off Leakage Current	I <sub>HSD2(OFF)</sub> I <sub>HSD1(OFF)</sub>	$V_{+} = 3.6V, V_{IS} = 3.3V/0.3V, V_{D} = 0.3V/3.3V$	Full			1	μΑ
Channel On Leakage Current	I <sub>HSD2(ON)</sub> , I <sub>HSD1(ON)</sub>	$V_{+} = 3.6V$ , $V_{IS} = 3.3V/0.3V$ , $V_{D} = 3.3V/0.3V$ or floating	Full			1	μΑ
Digital Inputs							
Input High Voltage	V <sub>IH</sub>		Full	1.6			V
Input Low Voltage	V <sub>IL</sub>		Full			0.5	V
Input Leakage Current	I <sub>IN</sub>	$V_+ = 3V$ , $V_S$ , $V_{\overline{OE}} = 0V$ or $V_+$	Full			1	μA
Dynamic Characteristics							
Turn-On Time	t <sub>ON</sub>	$V_{IS} = 0.8V, R_{L} = 50\Omega, C_{L} = 10pF,$	+25°C		10		ns
Turn-Off Time	t <sub>OFF</sub>	Test Circuit 2	+25°C		22		ns
Break-Before-Make Time Delay	t <sub>D</sub>	$V_{IS}$ = 0.8V, $R_L$ = 50 $\Omega$ , $C_L$ = 10pF, Test Circuit 3	+25°C		4		ns
Propagation Delay	t <sub>PD</sub>	$R_L = 50\Omega$ , $C_L = 10pF$	+25°C		0.3		ns
Off Isolation	O <sub>ISO</sub>	Signal = 0dBm, $R_L$ = 50 $\Omega$ , f = 250MHz, Test Circuit 4	+25°C		-35		dB
Channel-to-Channel Crosstalk	X <sub>TALK</sub>	Signal = 0dBm, $R_L$ = 50 $\Omega$ , f = 250MHz, Test Circuit 5	+25°C		-41		dB
-3dB Bandwidth	BW	Signal = 0dBm, $R_L$ = 50 $\Omega$ , $C_L$ = 5pF, Test Circuit 6	+25°C		550		MHz
Channel-to-Channel Skew	t <sub>skew</sub>	$R_L = 50\Omega$ , $C_L = 10pF$	+25°C		0.05		ns
Charge Injection Select Input to Common I/O	Q	$V_G$ = GND, $C_L$ = 1nF, $R_G$ = 0 $\Omega$ , $Q$ = $C_L$ × $V_{OUT}$ , Test Circuit 7	+25°C		11		pC
HSD+, HSD-, D+, D- On Capacitance	C <sub>ON</sub>		+25°C		6.5		pF
Power Requirements					ı		
Power Supply Range	V <sub>+</sub>		Full	1.8		4.3	V
Power Supply Current	I <sub>+</sub>	$V_{+} = 3V, V_{S}, V_{\overline{OE}} = 0V \text{ or } V_{+}$	Full			1	μΑ

# TYPICAL PERFORMANCE CHARACTERISTICS

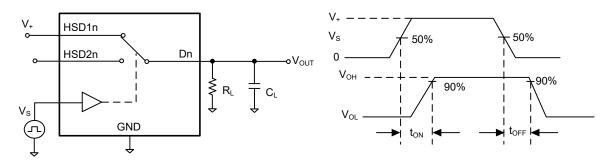




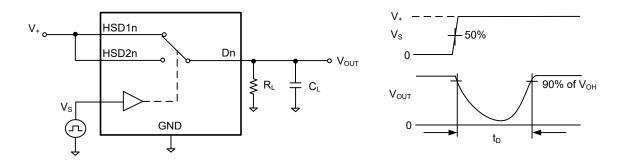
## **TEST CIRCUITS**



Test Circuit 1. On-Resistance

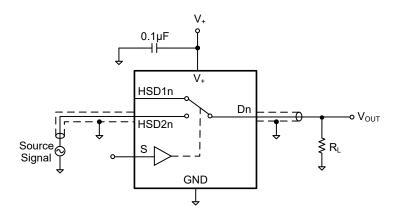


Test Circuit 2. Switching Times ( $t_{\text{ON}}$ ,  $t_{\text{OFF}}$ )

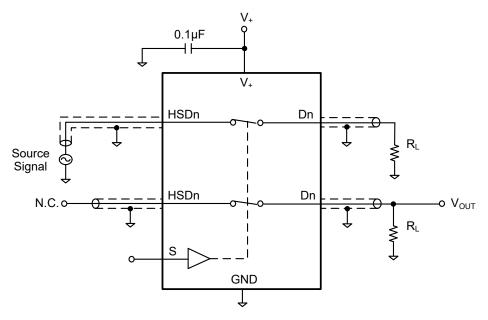


Test Circuit 3. Break-Before-Make Time (t<sub>D</sub>)

# **TEST CIRCUITS (continued)**



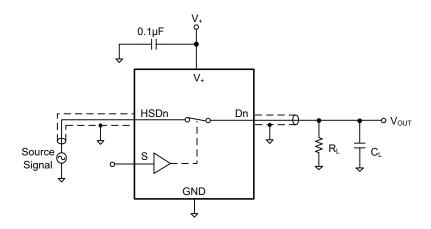
**Test Circuit 4. Off Isolation** 



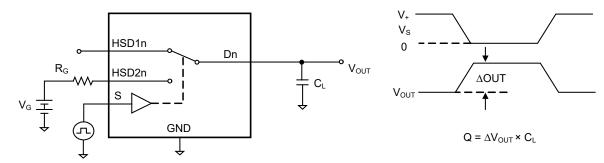
Channel To Channel Crosstalk = -20 × log  $\frac{V_{HSDn}}{V_{OUT}}$ 

Test Circuit 5. Channel-to-Channel Crosstalk

# **TEST CIRCUITS (continued)**



Test Circuit 6. -3dB Bandwidth



Test Circuit 7. Charge Injection (Q)

#### **APPLICATION NOTES**

#### Meeting USB 2.0 V<sub>BUS</sub> Short Requirements

In section 7.1.1 of the USB 2.0 specification, it notes that USB devices must be able to withstand a  $V_{\text{BUS}}$  short to D+ or D- when the USB devices is either powered off or powered on. The SGM7222 can be successfully configured to meet both these requirements.

#### **Power-Off Protection**

For a  $V_{\text{BUS}}$  short circuit the switch is expected to withstand such a condition for at least 24 hours. The SGM7222 has specially designed circuitry which prevents unintended signal bleed through as well as guaranteed system reliability during a power-down,

over-voltage condition. The protection has been added to the common pins (D+, D-).

#### **Power-On Protection**

The USB 2.0 specification also notes that the USB device should be capable of withstanding a  $V_{BUS}$  short during transmission of data. This modification works by limiting current flow back into the  $V_{+}$  rail during the over-voltage event so current remains within the safe operating range. In this application, the switch passes the full 5.25V input signal through to the selected output, while maintaining specified off isolation on the un-selected pins.

#### SGM7222 USB2.0 Signal Quality Compliance Tests

Figures 1 and 2 show the test results for USB eye diagram tests. A summary of the USB tests is provided in Table 1. The SGM7222 passes the high speed signal quality, eye diagram and jitter tests.

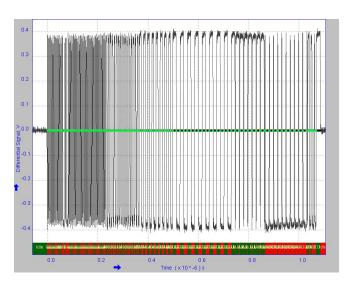


Figure 1. Waveform Plot

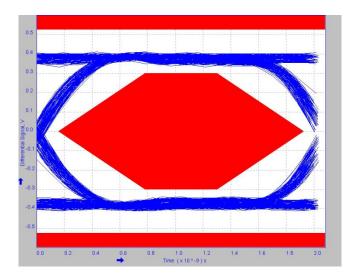


Figure 2. High Speed Signal Quality Eye Diagram Test (V<sub>+</sub> = 3.3V)

# **APPLICATION NOTES (continued)**

Table 1. Summary of the USB 2.0 Signal Quality Tests Results

Measurement Name	MIN	MAX	Mean	pk-pk	Standard Deviation	RMS	Population	Status
Eye Diagram Test	-	-	-	-	-	-	-	Pass
Signal Rate	469.9358 Mbps	493.4413 Mbps	479.9700 Mbps	0.0000 bps	5.586580 Mbps	480.4200 Mbps	512	Pass
EOP Width	-	-	16.58804ns	-	-	-	1	Pass
EOP Width (Bits)	-	-	7.961762	-	-	-	1	Pass
Falling Edge Rate	1.064231 kV/µs	1.228955 kV/µs	1.143136 kV/µs	164.7235 V/μs	35.43800 V/µs	1.143680 kV/µs	107	Pass
Rising Edge Rate	1.063269 kV/µs	1.227966 kV/µs	1.136558 kV/µs	164.6970 V/μs	31.49494 V/µs	1.136990 kV/µs	108	Pass

#### Additional Information:

Consecutive Jitter range: -82.97ps to 72.87ps RMS Jitter 35.08ps KJ Paired Jitter range: -25.05ps to 23.05ps RMS Jitter 9.259ps JK Paired Jitter range: -20.96ps to 30.12ps RMS Jitter 9.734ps

Rising Edge Rate: 1.136558kV/µs (Equivalent Rise Time = 563.10ps)
Falling Edge Rate: 1.143136kV/µs (Equivalent Fall Time = 559.86ps)

#### **REVISION HISTORY**

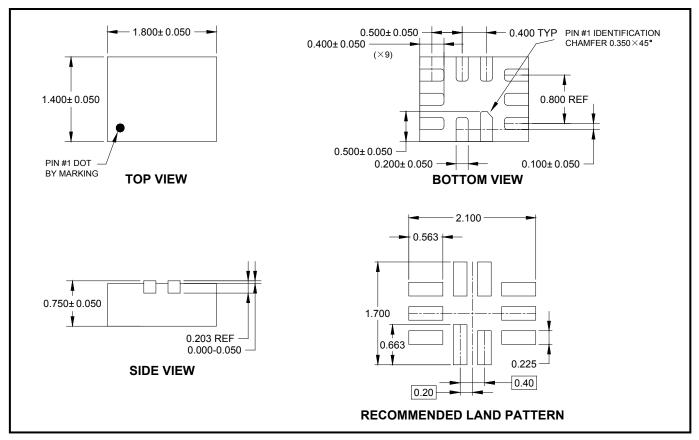
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

APRIL 2019 – REV.B.2 to REV.B.3	Page
Updated Package/Ordering Information section	2
MAY 2014 - REV.B.1 to REV.B.2	Page
Updated Absolute Maximum Ratings section	2
JANUARY 2013 – REV.B to REV.B.1	Page
Added Recommended Land Pattern section	, -,
MAY 2011 - REV.A.3 to REV.B	Page
Updated package option	All
MARCH 2011 – REV.A.2 to REV.A.3	Page
Updated Package Outline Dimensions section	12, 13, 14
FEBRUARY 2010 – REV.A.1 to REV.A.2	Page
Updated Test Circuits section	6, 8
SEPTEMBER 2009– REV.A to REV.A.1	Page
Added new package	
Changes from Original (DECEMBER 2008) to REV.A	Page



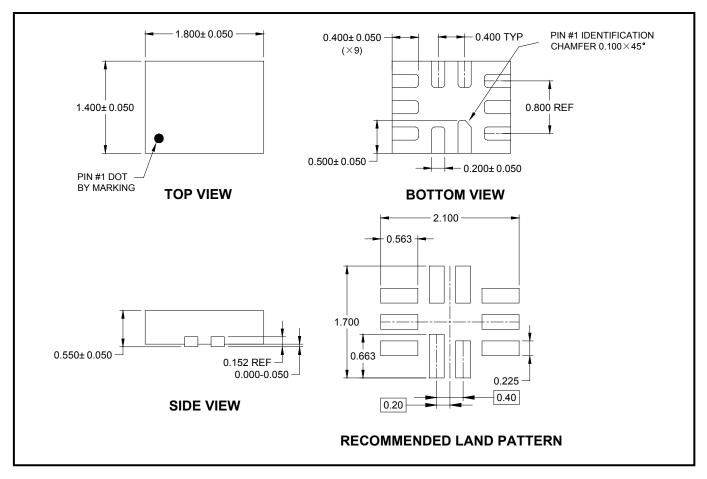
# **PACKAGE OUTLINE DIMENSIONS**

# TQFN-1.8×1.4-10L



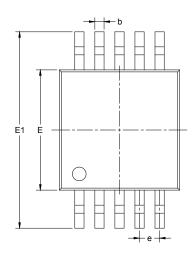
NOTE: All linear dimensions are in millimeters.

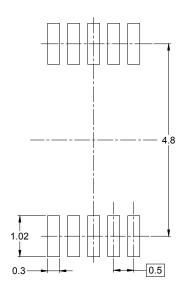
# PACKAGE OUTLINE DIMENSIONS UTQFN-1.8×1.4-10L



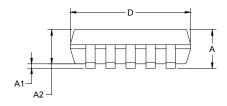
NOTE: All linear dimensions are in millimeters.

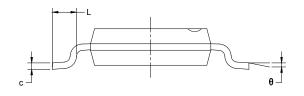
# PACKAGE OUTLINE DIMENSIONS MSOP-10





RECOMMENDED LAND PATTERN (Unit: mm)

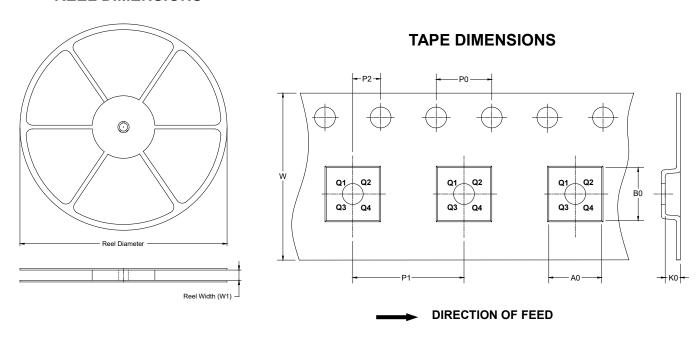




Symbol		nsions meters	Dimensions In Inches		
	MIN	MAX	MIN	MAX	
А	0.820	1.100	0.032	0.043	
A1	0.020	0.150	0.001	0.006	
A2	0.750	0.950	0.030	0.037	
b	0.180	0.280	0.007	0.011	
С	0.090	0.230	0.004	0.009	
D	2.900	3.100	0.114	0.122	
E	2.900	3.100	0.114	0.122	
E1	4.750	5.050	0.187 0.199		
е	0.500	BSC	0.020	BSC	
L	0.400	0.800	0.016	0.031	
θ	0°	6°	0°	6°	

# TAPE AND REEL INFORMATION

#### **REEL DIMENSIONS**

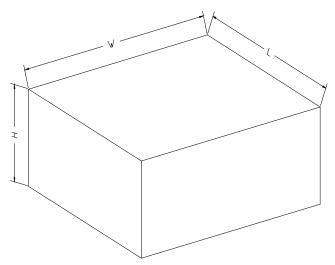


NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
TQFN-1.8×1.4-10L	7"	9.0	1.75	2.10	1.00	4.0	4.0	2.0	8.0	Q1
UTQFN-1.8×1.4-10L	7"	9.0	1.75	2.10	0.70	4.0	4.0	2.0	8.0	Q1
MSOP-10	13"	12.4	5.20	3.30	1.20	4.0	8.0	2.0	12.0	Q1

#### **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

#### **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18
13"	386	280	370	5